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**Wang et al.**

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(54) **PROGRAMMABLE ON-CHIP  
DIFFERENTIAL TERMINATION  
IMPEDANCE**

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**H03K 19/003** (2006.01)

(52) **U.S. Cl.** ..... **326/30; 326/31; 333/32**

(58) **Field of Classification Search** ..... **326/30,**  
**326/26, 31**

See application file for complete search history.

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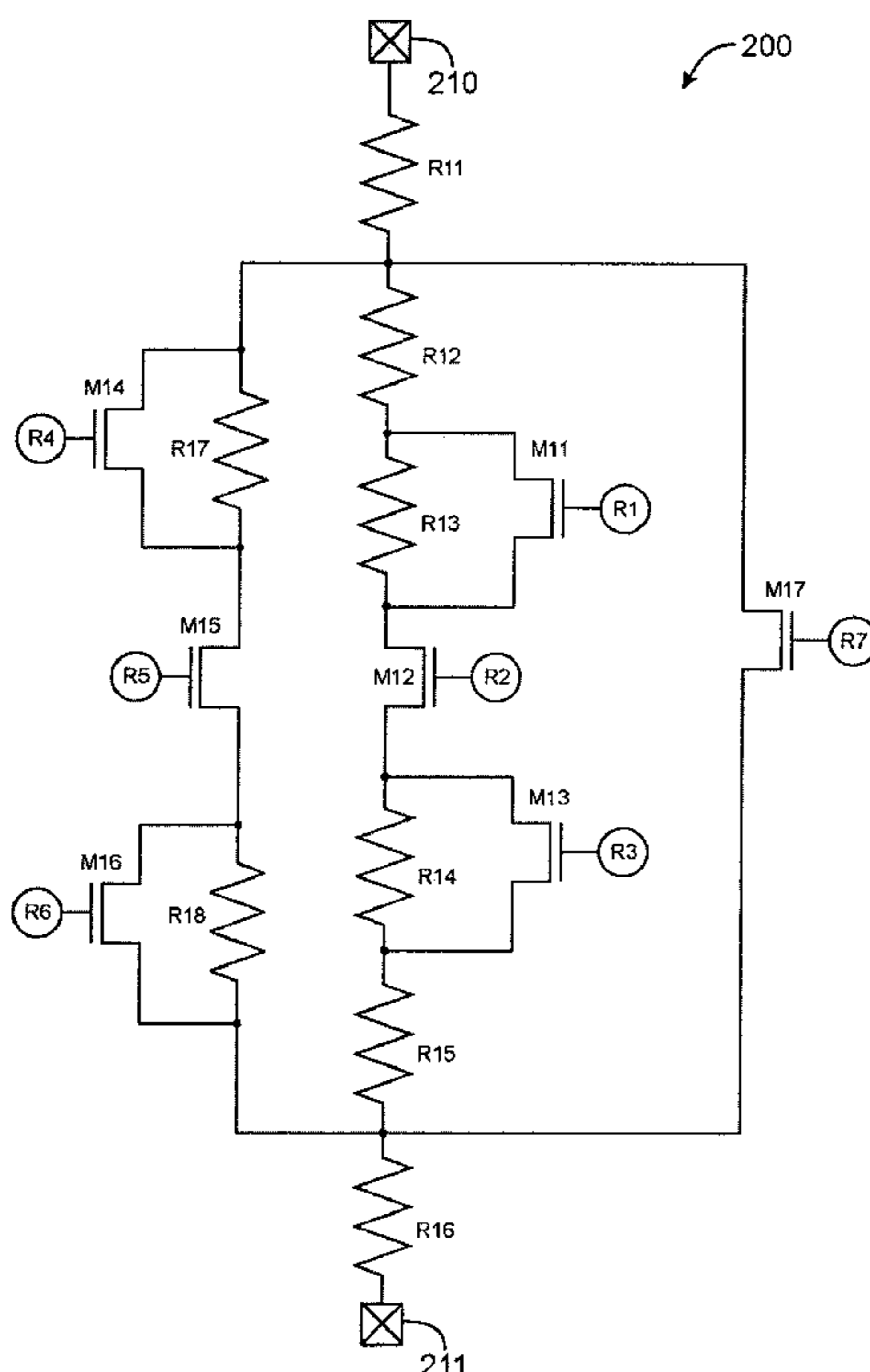
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(57) **ABSTRACT**

The circuits and methods are provided for impedance termination on an integrated circuit. A network of resistors are formed on an integrated circuit (IC) to provide on-chip impedance termination to differential input/output (IO) pins. Transistors are coupled in the network of termination resistors. The transistors provide additional termination impedance to the differential IO pins. The transistors can be turned ON or OFF separately to change the impedance termination.

**11 Claims, 3 Drawing Sheets**



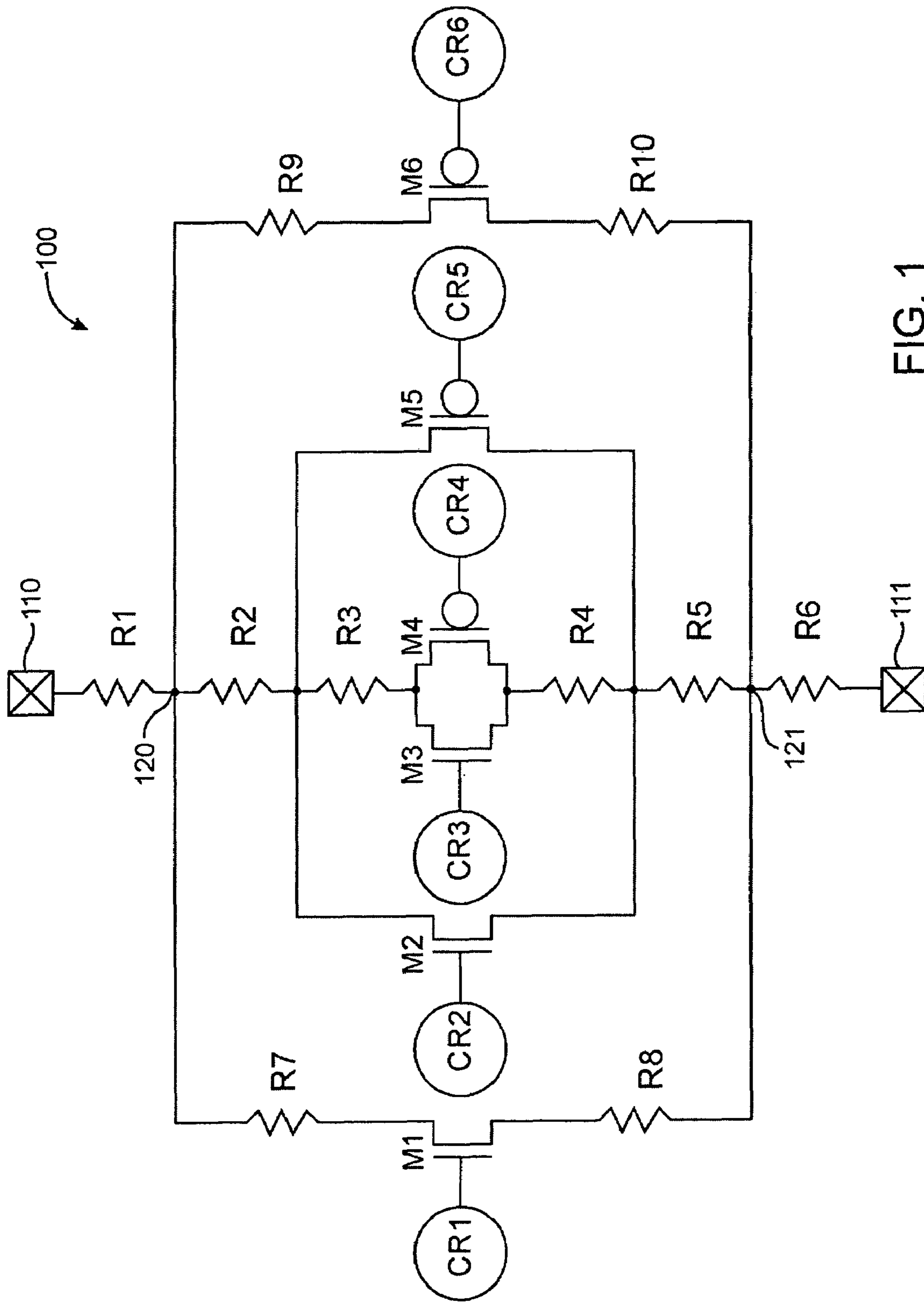


FIG. 1



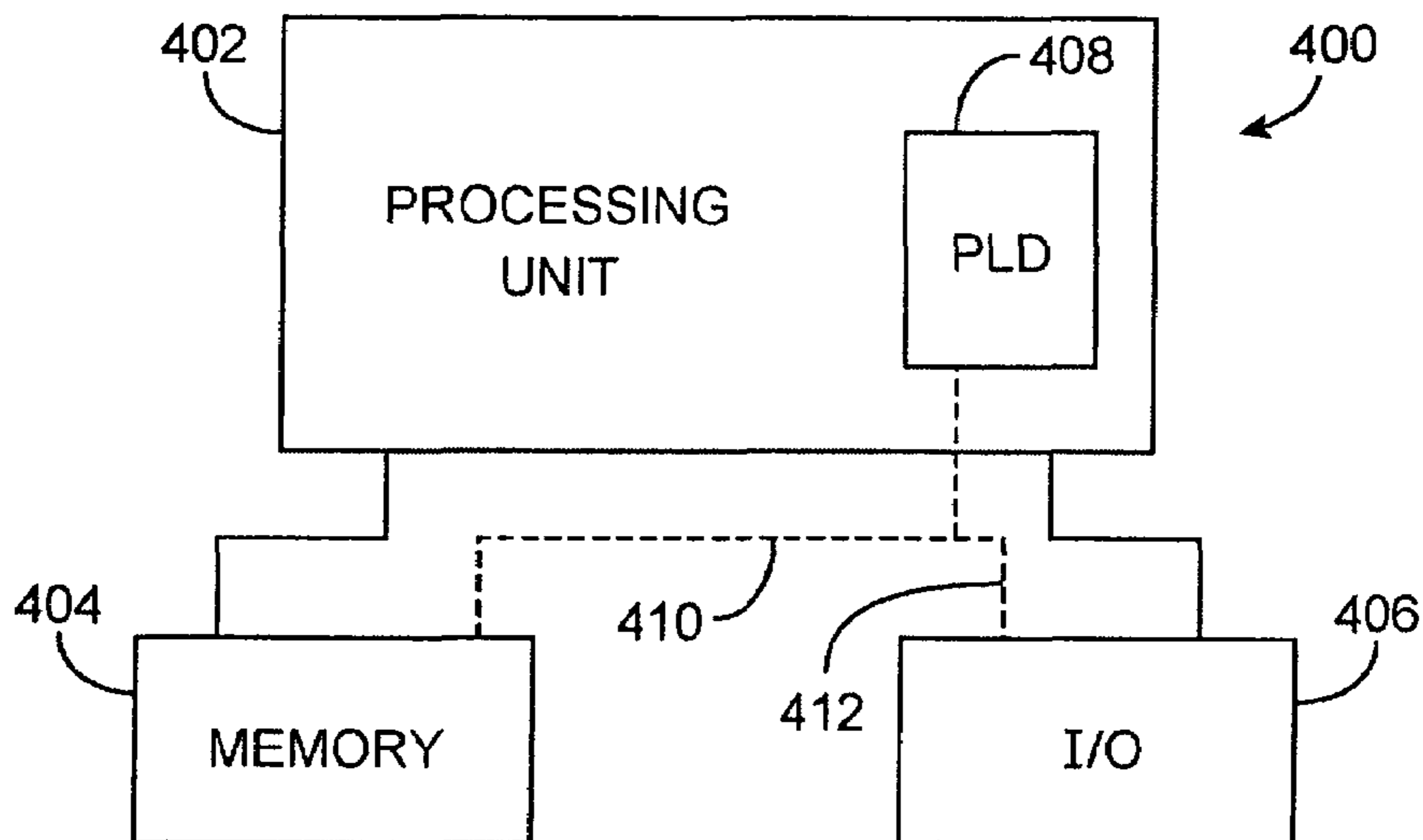
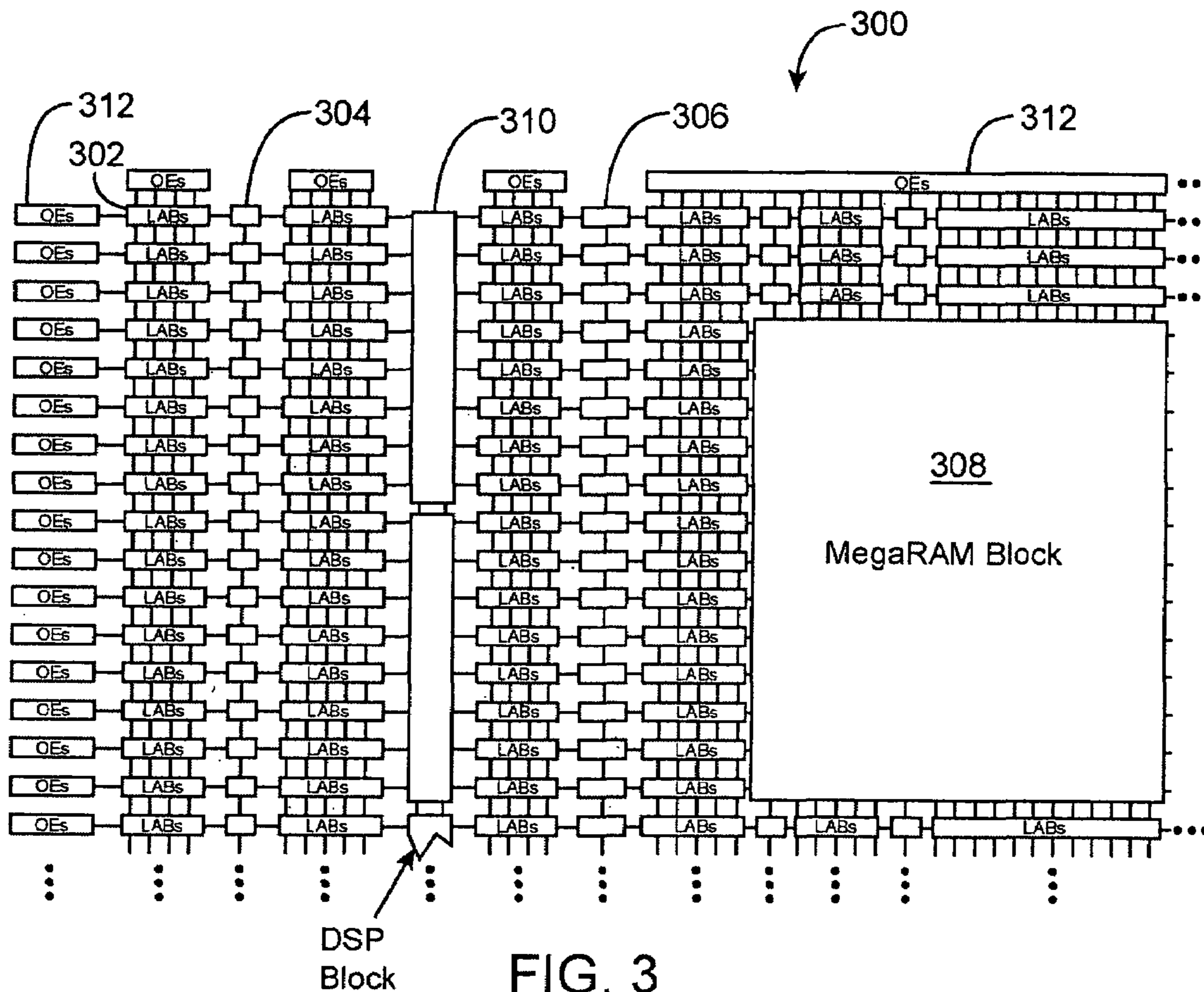


FIG. 4

## 1

**PROGRAMMABLE ON-CHIP  
DIFFERENTIAL TERMINATION  
IMPEDANCE**

CROSS-REFERENCES TO RELATED  
APPLICATIONS

This application is a continuation of U.S. patent application Ser. No. 10/622,314 filed Jul. 17, 2003, now U.S. Pat. No. 6,888,369, which is incorporated by reference herein.

BACKGROUND OF THE INVENTION

The present invention relates to techniques for providing on-chip termination impedance, and more particularly, to techniques for providing on-chip termination impedance to differential input/output pins.

Integrated circuits have input/output (IO) pins that are used to transmit signals into and out of the circuit. An external termination resistor is usually coupled to each IO pin to provide impedance termination. An impedance termination resistor reduces reflection of input signals on signal lines coupled to the IO pin.

However, external resistors typically use a substantial amount of board space. Therefore, it would be desirable to provide a technique for providing impedance termination for IO pins in an integrated circuit that does not occupy as much board space.

Prior art integrated circuit have provided on-chip termination impedance by coupling a field-effect transistor to an IO pin. The gate voltage of the transistor is controlled by a calibration circuit to regulate the impedance of the on-chip transistor. On-chip transistors have also been applied across differential IO pins to provide impedance termination.

The impedance of on-chip transistors are sensitive to process, voltage, and temperature variations on the integrated circuit. Therefore, it would be desirable to provide on-chip impedance termination that is less sensitive to process, voltage, and temperature variations on an integrated circuit.

BRIEF SUMMARY OF THE INVENTION

The present invention provides circuits and methods for providing impedance termination on an integrated circuit. According to the present invention, a network of resistors are formed on an integrated circuit (IC) to provide on-chip impedance termination to differential input/output (IO) pins. Transistors are coupled in the network of termination resistors. The transistors provide additional termination impedance to the differential IO pins. The transistors can be turned ON or OFF separately to change the impedance termination.

Other objects, features, and advantages of the present invention will become apparent upon consideration of the following detailed description and the accompanying drawings, in which like reference designations represent like features throughout the figures.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 illustrates an on-chip impedance termination circuit for differential IO pins according to a first embodiment of the present invention;

FIG. 2 illustrates an on-chip impedance termination circuit for differential IO pins according to a second embodiment of the present invention;

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FIG. 3 is a simplified block diagram of a programmable logic device that can implement embodiments of the present invention; and

FIG. 4 is a block diagram of an electronic system that can implement embodiments of the present invention.

DETAILED DESCRIPTION OF THE  
INVENTION

FIG. 1 illustrates a first embodiment of the present invention. Impedance termination circuit **100** of FIG. 1 is an on-chip circuit that is coupled between two differential IO pins **110–111**. Circuit **100** can be formed on an integrated circuit such as an ASIC, a programmable logic device, a field programmable gate array, a programmable logic array, a configurable logic array, etc.

Impedance termination circuit **100** includes resistors **R1–R10** and field-effect transistors **M1–M6**. Any suitable resistor values and transistor sizes can be used in an impedance termination circuit of the present invention. The gates of transistors **M1–M6** are coupled to six different memory cells **CR1–CR6**, respectively. Each of transistors **M1–M6** is turned ON and OFF separately by bits stored in memory cells **CR1–CR6**.

Transistors **M1–M6** can be turned ON and OFF by setting the values of the bits stored in memory cells **CR1–CR6**. Memory cells **CR1–CR6** can be programmed by a user of the integrated circuit or by a manufacturer of the integrated circuit. Alternatively, **CR1–CR6** can be coupled to external IO pins so that the bits stored in these memory cells can be set and reset by a user.

When memory cells **CR1–CR3** are HIGH, n-channel transistors **M1–M3** are ON. When memory cells **CR1–CR3** are LOW, n-channel transistors **M1–M3** are OFF. When memory cells **CR4–CR6** are HIGH, p-channel transistors **M4–M6** are OFF. When memory cells **CR4–CR6** are LOW, p-channel transistors **M4–M6** are ON. Any of n-channel transistors **M1–M3** can be substituted with p-channel transistors, and any of p-channel transistors **M4–M6** can be substituted with n-channel transistors.

Memory cells **CR1–CR6** turn transistors **M1–M6** ON and OFF to control the impedance of circuit **100**. For example, when all of transistors **M1–M6** are OFF, the impedance of circuit **100** is infinite in an open circuit condition.

When transistors **M1–M2** and **M4–M6** are OFF, and transistor **M3** is ON, the termination resistance of circuit **100** equals the combined resistance of **R1–R6** plus the ON drain-source resistance of transistor **M3**. Transistor **M4** can be turned ON to reduce the resistance added by **M3**. When transistors **M3** and **M4** are ON, their ON resistances are coupled in parallel and added to the total impedance of circuit **100**.

Transistors **M2** and/or **M5** can be turned ON by setting memory bits in cells **CR2** and **CR5** to reduce the resistance of circuit **100**. When transistors **M2** and **M5** are ON, their ON resistances are coupled in parallel with resistors **R3** and **R4** and transistors **M3–M4**. If desired, only one of transistors **M2** or **M5** can be turned ON to provide a smaller reduction in the total resistance of circuit **100**.

Transistors **M1** and/or **M6** can also be turned ON by setting bits in cells **CR1** and **CR6** to set the resistance of circuit **100**. When transistor **M1** is ON, resistors **R7** and **R8** and the ON resistance of transistor **M1** are coupled in series. The sum of these three resistances is coupled in parallel with the resistances between node **120** and node **121**.

When transistor **M6** is ON, resistors **R9** and **R11** and the ON resistance of transistor **M6** are coupled in series. The

sum of these three resistances is also coupled in parallel with the resistances between nodes **120** and **121**.

A user the circuit **100** can turn anyone or more of transistors **M1–M6** ON or OFF independently to increase or decrease the total resistance of circuit **100**. The present invention also a user to accurately change the resistance of an on-chip impedance termination circuit by setting bits **CR1–CR6** to turn ON or OFF transistors **M1–M6**. To illustrate, assume that all of resistors **R1–R10** are 10 ohms, and the ON resistance of transistors **M1–M6** is 10 ohms. If transistors **M1, M2, M3, M5, and M6** are OFF and transistor **M4** is ON, the total resistance of circuit **100** is  $R1+R2+R3+R_{M4}+R4+R5+R6=70$  ohms.

Transistor **M3** can be turned ON to decrease the resistance of circuit **100**. When transistor **M3** is ON, the resistance of circuit **100** is  $R1+R2+R3+R_{M3||M4}+R4+R5+R6=65$  ohms, where  $R_{M3||M4}$  equals

$$\frac{R_{M3}R_{M4}}{R_{M3} + R_{M4}}$$

Transistor **M2** can be turned ON to further decrease the resistance of circuit **100**. When transistor **M2** is ON, the resistance of circuit **100** is  $R1+R2+R_X+R5+R6=47.14$  ohms, wherein  $R_X$  equals

$$\frac{R_{M2}(R_3 + R_{M3||M4} + R_4)}{R_{M2} + R_3 + R_4 + R_{M3||M4}}$$

When transistor **M1** is ON, the resistance of circuit **100** is  $R1+$

$$\frac{(R_7 + R_8 + R_{M1})(R_2 + R_X + R_5)}{R_7 + R_8 + R_{M1} + R_2 + R_X + R_5} + R_6 = 34.25.$$

Transistors **M5** and **M6** can also be turned ON to further decrease the resistance of circuit **100**.

As another example, transistor **M6** and/or **M1** are ON, and transistors **M2–M5** are OFF. As still another example, transistor **M2** and/or **M5** are ON, and transistors **M1, M3–M4, and M6** are OFF. Many other examples are possible.

The resistance of resistors is less sensitive to process, voltage, and temperature variations on an integrated circuit than the ON resistance of transistors. Because resistors **R1–R9** provide most of the termination resistance on circuit **100**, the termination impedance of circuit **100** is less sensitive to variations in process, voltage, and temperature.

FIG. **2** illustrates a second embodiment of the present invention. Impedance termination circuit **200** of FIG. **2** includes resistors **R11–R18** and n-channel transistors **M11–M17**. N-channel transistors **M11–M17** are controlled by memory cells **R1–R7**, respectively. A user or a manufacturer stores bits (voltages) in memory cells **R1–R7** to select the impedance termination of circuit **200**.

If desired, any of n-channel transistors **M1–M17** can be substituted for p-channel transistors. Circuit **200** is coupled between differential IO pins **210–211**. Transistors **M12, M15, and M17** can be turned OFF to create an infinite impedance (an open circuit condition) in circuit **200**.

When transistors **M11, M13, M15, and M17** are OFF, the total resistance of circuit **200** is  $R11+R12+R13+R14+R15+R16+R_{M12}$ . Any appropriate resistance values can be

selected for **R11–R18**. Any one or more of transistors **M11–M17** can be turned ON to reduce the resistance of circuit **200**. For example, transistor **M11** can be turned ON to reduce the net resistance across **R13**. As another example, transistor **M17** can be turned ON to reduce the net resistance across resistors **R12–R15**. As another example, a user can select the impedance of circuit **100** or **200** to match the impedance of transmission lines coupled to the differential IO pins to reduce or eliminate reflection on the transmission lines.

Separate impedance termination circuits such as the embodiments shown in FIGS. **1** and **2** can be provided across each pair of differential IO pins on an integrated circuit.

FIGS. **1** and **2** are merely two examples of the impedance termination circuits of the present invention and are not intended to limit the scope of the present invention. The present invention also includes many different variations and embodiments of selectable on-chip termination impedance circuits coupled between differential IO pins. On-chip impedance termination circuits of the present invention can be fabricated on an integrated circuit such as a ASIC, a field programmable gate array (FPGA), or a programmable logic device (PLD).

FIG. **3** is a simplified partial block diagram of an exemplary high-density PLD **300** wherein impedance termination circuits the present invention can be utilized. PLD **300** includes a two-dimensional array of programmable logic array blocks (or LABs) **302** that are interconnected by a network of column and row interconnects of varying length and speed. LABs **302** include multiple (e.g., 10) logic elements (or LEs), an LE being a small unit of logic that provides for efficient implementation of user defined logic functions.

PLD **300** also includes a distributed memory structure including RAM blocks of varying sizes provided throughout the array. The RAM blocks include, for example, 512 bit blocks **304**, 4K blocks **306** and a MegaBlock **308** providing 512K bits of RAM. These memory blocks can also include shift registers and FIFO buffers. PLD **300** further includes digital signal processing (DSP) blocks **310** that can implement, for example, multipliers with add or subtract features. I/O elements (IOEs) **312** located, in this example, around the periphery of the device support numerous single-ended and differential I/O standards. It is to be understood that PLD **300** is described herein for illustrative purposes only and that the present invention can be implemented in many different types of PLDs, FPGAs, and the like.

While PLDs of the type shown in FIG. **3** provide many of the resources required to implement system level solutions, the present invention can also benefit systems wherein a PLD is one of several components. FIG. **4** shows a block diagram of an exemplary digital system **400**, within which the present invention can be embodied. System **400** can be a programmed digital computer system, digital signal processing system, specialized digital switching network, or other processing system. Moreover, such systems can be designed for a wide variety of applications such as telecommunications systems, automotive systems, control systems, consumer electronics, personal computers, Internet communications and networking, and others. Further, system **400** can be provided on a single board, on multiple boards, or within multiple enclosures.

System **400** includes a processing unit **402**, a memory unit **404** and an I/O unit **406** interconnected together by one or more buses. According to this exemplary embodiment, a programmable logic device (PLD) **408** is embedded in

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processing unit **402**. PLD **408** can serve many different purposes within the system in FIG. 4. PLD **408** can, for example, be a logical building block of processing unit **402**, supporting its internal and external operations. PLD **408** is programmed to implement the logical functions necessary to carry on its particular role in system operation. PLD **408** can be specially coupled to memory **404** through connection **410** and to I/O unit **406** through connection **412**.

Processing unit **402** can direct data to an appropriate system component for processing or storage, execute a program stored in memory **404** or receive and transmit data via I/O unit **406**, or other similar function. Processing unit **402** can be a central processing unit (CPU), microprocessor, floating point coprocessor, graphics coprocessor, hardware controller, microcontroller, programmable logic device programmed for use as a controller, network controller, and the like. Furthermore, in many embodiments, there is often no need for a CPU.

For example, instead of a CPU, one or more PLDs **408** can control the logical operations of the system. In an embodiment, PLD **408** acts as a reconfigurable processor, which can be reprogrammed as needed to handle a particular computing task. Alternately, programmable logic device **408** can itself include an embedded microprocessor. Memory unit **404** can be a random access memory (RAM), read only memory (ROM), fixed or flexible disk media, PC Card flash disk memory, tape, or any other storage means, or any combination of these storage means.

While the present invention has been described herein with reference to particular embodiments thereof, a latitude of modification, various changes, and substitutions are intended in the present invention. In some instances, features of the invention can be employed without a corresponding use of other features, without departing from the scope of the invention as set forth. Therefore, many modifications can be made to adapt a particular configuration or method disclosed, without departing from the essential scope and spirit of the present invention. It is intended that the invention not be limited to the particular embodiment disclosed, but that the invention will include all embodiments and equivalents falling within the scope of the claims.

What is claimed is:

1. An integrated circuit comprising:
  - a first pad;
  - a second pad;
  - a differential buffer coupled to the first pad and the second pad; and
  - a differential termination impedance circuit coupled between the first pad and the second pad and comprising:

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- a first resistance;
  - a second resistance having a first terminal connected directly to a first terminal of the first resistance;
  - a first active device having a first source/drain region connected directly to the first terminal of the first resistance and the first terminal of the second resistance; and
  - a second active device having a first source/drain region coupled to a second terminal of the second resistance;
  - a third resistance having a first terminal coupled to a second source/drain region of the second active device and a second terminal directly connected to a second source/drain region of the first active device; and
  - a third active device having a first source/drain region coupled to the second terminal of the second resistance and a second source/drain region coupled to the first terminal of the third resistance.
2. The integrated circuit of claim 1 wherein the first and second resistances each consist of a single resistor.
  3. The integrated circuit of claim 1 wherein the first and second resistances each consist of a plurality of resistors.
  4. The integrated circuit of claim 1 further comprising:
    - a storage cell coupled to the gate of the first active device.
  5. The integrated circuit of claim 4 wherein the storage cell is a memory cell.
  6. The integrated circuit of claim 1 further comprising:
    - a fourth resistance having a first terminal directly connected to the second terminal of the third resistance and the second source/drain region of the first active device.
  7. The integrated circuit of claim 1 wherein the differential buffer is an input buffer.
  8. The integrated circuit of claim 1 wherein the differential buffer is an output buffer.
  9. The integrated circuit of claim 1 further comprising:
    - a plurality of programmable logic elements; and
    - a plurality of programmable interconnect lines, wherein the programmable logic elements and programmable interconnect lines are configurable to implement user-defined logic functions.
  10. The integrated circuit of claim 1 further comprising:
    - a first memory cell coupled to the gate of the first active device; and
    - a second memory cell coupled to the gate of the second active device.
  11. The integrated circuit of claim 1 wherein the integrated circuit is a field programmable gate array.

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